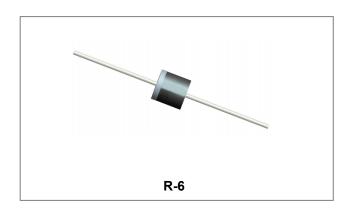






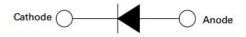
ST2050AX SCHOTTKY BARRIER RECTIFIER



Features

- 150°C T_J operation
- Center tap configuration
- Ultralow forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- · High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	-	50	V
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @T _C = 75°C, rectangular wave form	20	Α
Peak One Cycle Non-Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine pulse, T _C = 25°C	250	А

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 10A, Pulse, T _J = 25 °C @ 20A, Pulse, T _J = 25 °C	0.47 0.52	- 0.65	V
	V _{F2}	@ 10A, Pulse, T _J = 125 °C @ 20A, Pulse, T _J = 125 °C	0.38 0.48	- 0.60	V
Reverse Current*	I _{R1}	@V _R = rated V _R , T _J = 25 °C	0.03	4	mA
	I _{R2}	@V _R = rated V _R , T _J = 125 °C	30	180	mA
Junction Capacitance	Ст	$@V_R = 5V, T_C = 25 °C$ $f_{SIG} = 1MHz$	1300	-	pF

 $^{^*}$ Pulse width < 300 μ s, duty cycle < 2%

- China Germany Korea Singapore United States •
- http://www.smc-diodes.com sales@ smc-diodes.com •



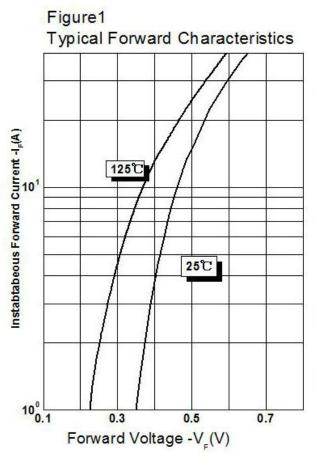


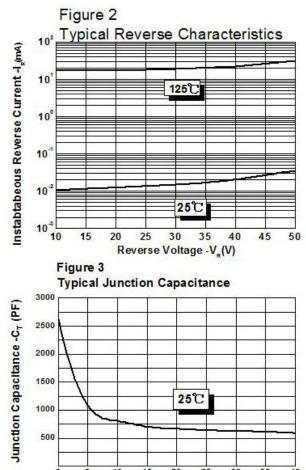


Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T _{stg}	-	-55 to +150	°C
Typical Thermal Resistance Junction to Ambient	$R_{ heta JA}$	DC operation	45	°C/W
Approximate Weight	wt	-	2.24	g
Case Style	R-6			

Ratings and Characteristics Curves





Reverse Voltage -V (V)

[•] China - Germany - Korea - Singapore - United States •

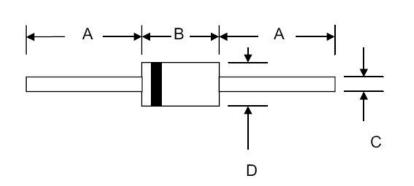
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Mechanical Dimensions R-6



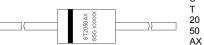
CYMPOL	Millimeters		Inches		
SYMBOL	Min.	Max.	Min.	Max.	
А	25.4	-	1.000	-	
В	8.60	9.10	0.340	0.360	
С	1.2	1.3	0.048	0.052	
D	8.60	9.10	0.340	0.360	

Ordering Information

Device	Package	Shipping
ST2050AX	R-6(Pb-Free)	500pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



Where XXXXX is YYWWL

Device Type
Ultralow VF
Forward Current (20A)

= Reverse Voltage (50V)

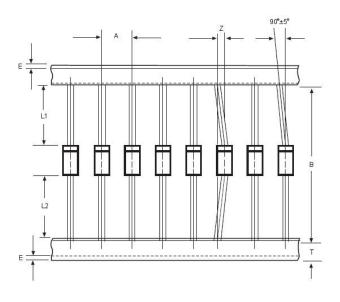
= Package type

SSG = SSG YY = Year

YY = Year WW = Week

= Lot Number

Carrier Tape Specification R-6



SYMBOL	Millimeters		
STWIBOL	Min.	Max.	
А	9.50	10.50	
В	50.9	53.9	
Z	-	1.20	
Т	5.60	6.40	
E	-	0.80	
IL1-L2I	-	1.0	

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